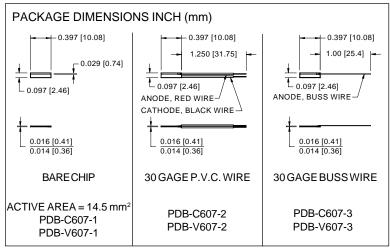
PHOTONIC Silicon Photodiode, Blue Enhanced Solderable Chips

Photoconductive Type PDB-C607 Photovoltaic Type PDB-V607





FEATURES

- Blue enhanced
- Photovoltaic type
- Photoconductive type
- High quantum efficiency

DESCRIPTION: Low cost blue enhanced planar diffused silicon solderable photodiode. The **PDB-V607** cell is designed

for low noise, photovoltaic applications. The PDB-C607 cell is

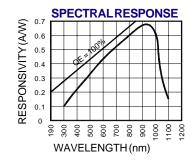
designed for low capacitance, high speed, photoconductive operation. They are available bare, PVC or buss wire leads.

APPLICATIONS

- Optical encoder
- Position sensor
- Industrial controls
- Instrumentation

ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

| SYMBOL | PARAMETER . | PDB-C607 | | PDB- | V607 | UNITS | |
|------------------|-----------------------------|----------|------|------|------|--------|--|
| | | MIN | MAX | MIN | MAX | 014110 | |
| VBR | Reverse Voltage | | 75 | | 25 | V | |
| T _{STG} | Storage Temperature | -40 | +125 | -40 | +125 | °C | |
| То | Operating Temperature Range | -40 | +100 | -40 | +100 | °C | |
| Ts | Soldering Temperature | | +224 | | +224 | °C | |
| I _L | Light Current | | 500 | | 500 | mA | |



ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

| SYMBOL | CHARACTERISTIC | TESTCONDITIONS | PDB-C607 | | | PDB-V607 | | | LINITO |
|--------|----------------------------|----------------------------------|---------------------------|-----|---------------------------|----------|------|--------|---------|
| | | | MIN | TYP | MAX | MIN | TYP | MAX | UNITS |
| Isc | Short Circuit Current | H = 100 fc, 2850 K | 165 | 185 | | 165 | 185 | | μ A |
| ΙD | Dark Current | H = 0, V _R = 5 V* | | 15 | 35 | | 25 | 50 | nA |
| Rsн | Shunt Resistance | H = 0, V _R = 10 mV | 6 | 15 | | 10 | 30 | | MΩ |
| TC Rsh | RsH Temp. Coefficient | H = 0, V _R = 10 mV | | -8 | | | -8 | | %/°C |
| CJ | Junction Capacitance | H = 0, V _R = 5 V** | | 125 | | | 2400 | | pF |
| λrange | Spectral Application Range | Spot Scan | 350 | | 1100 | 350 | | 1100 | nm |
| λр | Spectral Response - Peak | Spot Scan | | 940 | | | 940 | | nm |
| VBR | Breakdown Voltage | I = 10 μA | 50 | 100 | | 5 | 10 | | V |
| NEP | Noise Equivalent Power | V _R = 0 V @ Peak | 8 x 10 ⁻¹³ TYP | | 9 x 10 ⁻¹⁴ TYP | | | W/ √Hz | |
| tr | Response Time | RL = 1 KΩ V _R = 5 V** | | 25 | | | 1000 | | nS |

 $^{^*}VR = 100$ mV on Photovoltaic type $^{**}VR = 0$ V on Photovoltaic type